

- 4.12** (a) The carrier effective masses in a semiconductor are $m_n^* = 1.21 m_0$ and $m_p^* = 0.70 m_0$. Determine the position of the intrinsic Fermi level with respect to the center of the bandgap at $T = 300$ K.

Per (4.26b),

$$\begin{aligned} E_{F,i} - E_{\text{midgap}} &= \frac{3}{4} k_B T \ln \left(\frac{m_p^*}{m_n^*} \right) \\ &= 0.75 (8.617333 \times 10^{-5} \text{ eV/K}) 300 \text{ K} \ln \left(\frac{0.70 m_0}{1.21 m_0} \right) \\ &\Rightarrow \underline{\underline{E_{F,i} - E_{\text{midgap}} = -0.0106115 \text{ eV} = -1.7001511 \times 10^{-21} \text{ J}}} \end{aligned}$$